
MICROWAVES THERMAL SYNTHESIS AND CHARACTERIZATION OF MANGANESE-DOPED ZINC-OXIDE NANOPARTICLES

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ABSTRACT: Mn-doped zinc oxide nano-particles were prepared by using the microwave thermal synthesis (MSS) technique. The nanoparticles were produced from a solution of zinc acetate dihydrate and manganese (II) acetate tetra hydrate using ethylene glycol as solvent. The content of Mn^{2+} in $Zn_{1-x}Mn_xO$ ranged from 1 to 25 mol %. The following properties of the nanostructures were investigated: skeleton density, specific surface area (SSA), phase purity (XRD), lattice parameters, dopant content, average particle size, crystallite size distribution, morphology. The average particle size of $Zn_{1-x}Mn_xO$ was determined using Scherer's formula, the Nanopowder XRD Processor Demo web application and by converting the specific surface area results. X-ray diffraction of synthesized samples shows a single-phase wurtzite crystal structure of ZnO without any indication of additional phases. Spherical $Zn_{1-x}Mn_xO$ particles were obtained with monocrystalline structure and average particle sizes from 17 to 30 nm depending on the content of dopant. SEM images showed an impact of the dopant concentration on the morphology of the nanoparticles.

INTRODUCTION

Nanotechnology has triggered a new global industrial revolution of the 21st century [1]. At present it is the leading technology in various research fields such as chemistry, physics, biology, medicine, materials and biomedical engineering, optoelectronics and interdisciplinary fields. It is a technology that enables testing, controlling, producing and using structures at least one dimension of which is below 100 nanometres [2]. It enables the use of nanomaterials for creating innovative products, devices and complex systems that employ the properties of materials on the nanoscale [3]. Current research of the applications of nanotechnology in optoelectronics focuses on the control of the physical properties of metal oxides semiconductors Zinc oxide (ZnO) is a II–VI semiconductor characterized by a wide band gap of 3.3 eV and a high exciton binding energy of circa 60 meV [4]. ZnO is used in optoelectronic devices, solar cells, data carriers, light emitting diodes (LEDs), gas sensors, thermoelectric devices, varistors, TFT display windows and laser technology [5-7]. ZnO displays pyroelectric and piezoelectric properties, thanks to which it is used in electro acoustic devices [8]. It is a biocompatible material used for producing biosensors and in drug delivery applications [9]. Thanks to anti-bacterial activity, matting and hiding properties, as well as bleaching properties, it is applied in the pharmaceutical and cosmetic industry to produce creams, dressings, powders, baby powders and toothpastes. In pediatric dentistry, it is the primary ingredient of the temporary filling material [10]. It is also a popular mineral filter against UVA and UVB radiation [11-13]. The search for “doped ZnO” and “Mn doped ZnO” phrases in the “Science Direct” scientific search engine yielded 32,757 and 7,213 matches, respectively, (April 2016) in various research fields. The number of published scientific papers confirms the growing interest in Mn^{2+} -doped zinc oxide (Figure 1). It is generally known that selective doping enables controlling the semi-conductor properties of ZnO, such as forbidden band or conductivity. The diversity of ZnO modifications by doping with various transition metal ions (e.g., Co, Mn, Ni, Fe, Cr, V) considerably increases the capabilities of applying that material in electronics, spintronics and

optoelectronics [14-16]. Papers related to the magnetic properties of Mn²⁺-doped ZnO focus on the impact of homogeneity, phase purity and dopant content on the properties [17, 18]. In the case of substituting Zn²⁺ atoms by Mn²⁺ atoms in a ZnO crystalline lattice, an increase in the value of lattice parameters was observed [19,20]. The ionic radius of Mn²⁺ is 0.82 Å [21], which is greater than that of Zn²⁺ being 0.74 Å [18]. Therefore, Zn²⁺ can be substituted to a limited extent by Mn²⁺ [22]. Numerous scholars have described obtaining Mn²⁺-doped zinc oxide, which displays ferromagnetic properties at room temperature, in their papers [23-26]. However, there are many contradicting or even controversial publications on this topic [27-30]. Depending on the method of obtaining, Zn_{1-x}Mn_xO may display either ferromagnetic [31] or paramagnetic properties [32]. Various pieces of literature reporting magnetic properties of Zn_{1-x}Mn_xO NPs result from the impact of the synthesis method on: the heterogeneous distribution of Mn²⁺ ions in the ZnO crystalline lattice (e.g., formation of clusters [31]), the precipitation of foreign phases [33,34], the stoichiometry; the presence of oxygen vacancies [35,36], and defects of the crystalline lattice. When the synthesis or calcinations of Zn_{1-x}Mn_xO was carried out in an oxidizing environment and the absence of foreign phases was observed, the obtained material exhibited paramagnetic properties [29,33,37]. Whereas, when Zn_{1-x}Mn_xO was synthesized or calcinated for too long or at an overly high temperature, in an oxidizing atmosphere, foreign phases in the form of MnO, MnO₂, Mn₂O, Mn₃O₄, as well as products of the reaction of ZnO with Mn_xO_y such as ZnMnO₃ and ZnMn₂O₄ were precipitated in the material. The obtained Zn_{1-x}Mn_xO materials were characterized by either ferromagnetic or paramagnetic properties depending on the presence of foreign phases [33,36,38,39]. This result from different magnetic properties of Mn_xO_y and metallic Mn. Metallic manganese is antiferromagnetic, while many alloys of manganese, in which the average Mn–Mn distance is greater than that of metallic manganese, are ferromagnetic [40]. MnO, Mn₂O₃ and MnO₂ are antiferromagnetic [41],

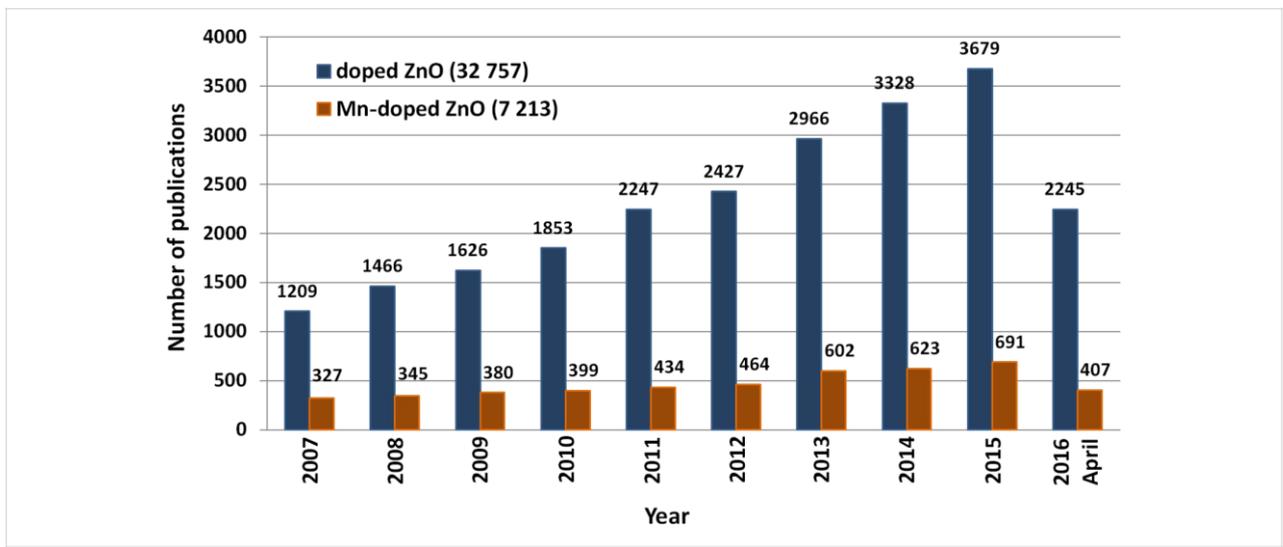


Figure 1: The number of scientific publications referring to the search of “doped ZnO” and “Mn doped ZnO” phrases published in the period 2007–2015. Source: Science Direct (accessed April 27, 2016).

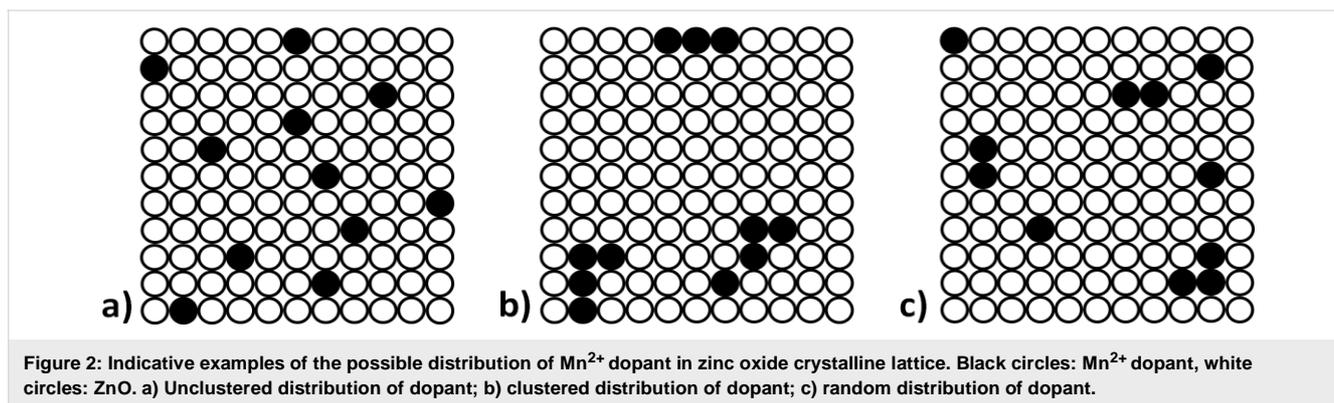
explains the various reports about obtaining Zn_{1-x}Mn_xO with different and in parts contradictory properties. The relevant literature describes several methods for the synthesis of Zn_{1-x}Mn_xO nanomaterials, in particular co-precipitation [49], coprecipitation–calcination [29], combustion [52], sol–gel [7,30], spin coating [19,20], pulsed laser deposition [26], reactions in the solid state [35], thermal evaporation [56], and thermal evaporation vapour-phase deposition [30]. However, two of the most promising methods, which are still being developed are hydrothermal and solvothermal synthesis [16]. The growing popularity of these methods is proved by the emergence of new types of reactors, e.g., microwave stop-flow and continuous-flow in supercritical water. Microwave solvothermal

synthesis (MSS) is quicker, purer, and more energy and cost efficient than conventional synthesis methods. The microwave radiation employed is a highly effective method of providing energy to the reaction chamber, which results in a more uniform and rapid heating in comparison with traditional methods of heat transfer. The MSS method is a “wet chemistry” method. This means that the precursor is obtained from solutions of substrates, which are mixed in precisely determined quantities, and the synthesis is carried out under controlled conditions (temperature, pressure, time). The synthesis product is a precipitate, which is mainly subjected to filtering, rinsing and drying. The advantages of the microwave solvothermal synthesis are purity (Teflon reaction chamber, contactless heating method), short process duration, precise control over parameters (time, pressure), product homogeneity (volumetric heating), control over dopant content, high efficiency, and surface modification. MSS products are characterized by homogeneous morphology, purity, narrow size distribution and low agglomeration

The present paper contains an attempt to obtain ZnO nano-particles with a Mn^{2+} dopant content of up to 25 mol %. For the synthesis we selected an organic solvent with weak reducing properties to prevent the precipitation of foreign phases, which is caused above all by the changed oxidization state of Mn^{2+} ions.

But when a reducing environment was selected for sample calcinations, also precipitations of $ZnMnO_3$ and $ZnMn_2O_4$ phase emerged in $Zn_{1-x}Mn_xO$ and the material displayed only ferromagnetic properties [36]. Ferromagnetic properties of $Zn_{1-x}Mn_xO$ are explained by the presence of oxygen vacancies, manganese in various oxidation states (II–IV), and dopant clusters. The formation of clusters of Mn^{2+} dopant in ZnO NPs, This, in turn, leads to different magnetic properties than those encountered in nanomaterials with the same dopant content but with a different distribution of ions or dopant clusters in the crystalline lattice (Figure 2) .

Despite the efforts made by numerous research groups and despite the development of new synthesis methods, obtaining nanomaterials with reproducible properties proves a very complex and problematic task. Obtaining $Zn_{1-x}Mn_xO$ nanomaterials with reproducible optoelectronic and magnetic properties remains an unsolved issue. Differing properties of the obtained $Zn_{1-x}Mn_xO$ result from the complexity of chemical reactions and the limitations of the currently employed methods. The lack of simultaneous control over chemical composition, stoichiometry, dopant homogeneity, particle size distribution, shape, phase purity, surface modification and agglomeration, makes it difficult to obtain NPs [22]. The primary cause of the lack of reproducibility of magnetic properties in the case of $Zn_{1-x}Mn_xO$ is the lack of control over the doping impact on the formation of oxygen vacancies, crystalline lattice defects and dopant clusters. It is presumed that there are several competitive chemical reactions in the reaction of $Zn_{1-x}Mn_xO$ synthesis, such as the oxidization of Mn^{2+} ions, the formation of Mn_xO_y , the reduction of Mn^{2+} ions to metallic Mn, and the reaction of Mn_xO_y with ZnO leading to the formation of spinels ($ZnMnO_3$, $ZnMn_2O_4$). These reactions may occur simultaneously depending on the synthesis method, the synthesis parameters and the method of precursor preparation. The microwave solvothermal synthesis was selected for obtaining $Zn_{1-x}Mn_xO$. It was shown before by us that the MSS method led to fully crystallized Co^{2+} -doped ZnO without foreign phases and with a uniform particle size and shape.



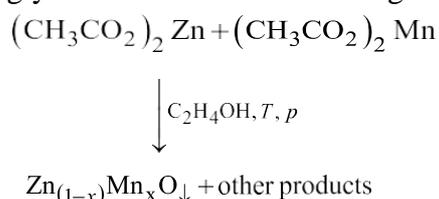
EXPERIMENTAL SUBSTRATES

Zinc acetate dehydrate (Zn(CH₃COO)₂·2H₂O), analytically pure, SKU: 112654906-1KG; ethylene glycol (1,2-ethanediol, C₂H₄(OH)₂), pure, SKU: 114466303-5L and manganese(II) acetate tetra hydrate (Mn(CH₃COO)₂·4H₂O), analytically pure, SKU: 116167509-100g were purchased from New Delhi. The reagents were used without additional purification.

$$D = N / SS.p$$

Synthesis of Zn_{1-x}Mn_xO NPs

Zn_{1-x}Mn_xO NPs were obtained by the MSS method. The precursor was obtained by dissolving powder mixtures, composed of 1, 5, 10, 15, 20, 25 mol % of manganese acetate in zinc acetate, in ethylene glycol (Table 1). The reference sample of ZnO was obtained from the precursor without adding the Mn²⁺ doping. The mixture of the acetates in glycol (75 mL) was heated to 70 °C and stirred using a magnetic stirrer (SLR, SI Analytics, Germany) until the components were completely dissolved. After cooling down to ambient temperature the solution was poured to the Teflon reaction chamber with a total volume of 110 mL [66]. The synthesis reaction initiated by microwave radiation was carried out in a microwave reactor (Model 02-02, 600 W, 2.45 GHz, ERTEC, Poland) at a temperature of 200 °C. The synthesis of Mn²⁺-doped zinc oxide in ethylene glycol can be described through the following equation:



server to extract the crystallite size distribution for XRD peaks. Unlike the standard fitting, the tool does not act in the reciprocal space at all, but solves sets of equations in a few auxiliary spaces simultaneously. This allows for an analysis of XRD data with heavily convoluted reciprocal space peaks [68,69].

MEASUREMENT OF DENSITY AND SPECIFIC SURFACE AREA

Density measurements were carried out using a helium pycnometer (AccuPyc II 1340 FoamPyc V1.06, Micromeritics, USA), in accordance with ISO 12154:2014 at the temperature of 25 ± 2 °C. The density of a material obtained using helium pycnometry is called, e.g., skeleton density, pycnometric density, true density and helium density in the relevant literature. The specific surface area of NPs was determined using the analysis of nitrogen adsorption isotherm by the BET

(Brunauer–Emmett–Teller) method (Gemini 2360, V 2.01, Micromeritics), in accordance with ISO 9277:2010. Prior to performing measurements of both density and specific surface area, the samples were subject to 2 h desorption in a desorption station (FlowPrep, 060 Micromeritics), at a temperature of 150 °C with a flow of helium of 99.999% purity. Based on the determined specific surface area and density, the average size of particles was determined, with the assumption that all particles are spherical and identical [70]. Equation 2 was used for calculating the average particle size, where D is the average diameter of the of particles [μm], N is a shape coefficient being ($N = 6$) for sphere, SSA is the specific surface area [m^2/g] and ρ the density [g/cm^3].

Morphologic characteristics

The morphology of NPs was determined using scanning electron microscopy (SEM) (ZEISS, Ultra Plus, Germany). The samples were coated with a thin carbon layer using a sputter coater (SCD 005/CEA 035, BAL-TEC, Switzerland).

Chemical composition analysis

The chemical composition analysis was carried out by using visible-light spectrophotometry (DR 3900, Hach Lange, Germany). The analysis of the content of Zn^{2+} ions was carried out by using the Zincon method No. 8009 (Hach Lange). The analysis of the content of Mn^{2+} ions was carried out by using the 1-(2-pyridylazo)-2-naphthol (PAN) method No. 8149 (Hach Lange). The chemical composition analysis was carried out by using inductively coupled argon plasma optical emission spectrometry (ICP-OES) (Thermo Scientific, iCAP model 6000, Great Britain). Samples for the quantitative analysis were prepared as follows: 5 mg of powder was weighed in a 110 mL

Teflon vessel and 15 mL of deionised water (HLP 20UV, Hydrolab, Poland) was added; then 6 mL of HNO_3 was added and the solution subjected to one microwave heating cycle in a Magnum II reactor (600 W, 2.45 GHz, ERTEC, Poland). After cooling the sample volume was filled up to 50 mL with deionized water. The pH of samples before the colorimetric analysis was adjusted in accordance with the recommendations of procedures No. 8009 and No. 8149. Quantitative microanalysis was carried out through energy- dispersive X-ray spectroscopy (EDS) by using an EDS analyzer (Quantax 400, Bruker, USA). Samples for EDS tests were pressed to pellets with a diameter of 5 mm.

RESULTS AND DISCUSSION

MORPHOLOGY

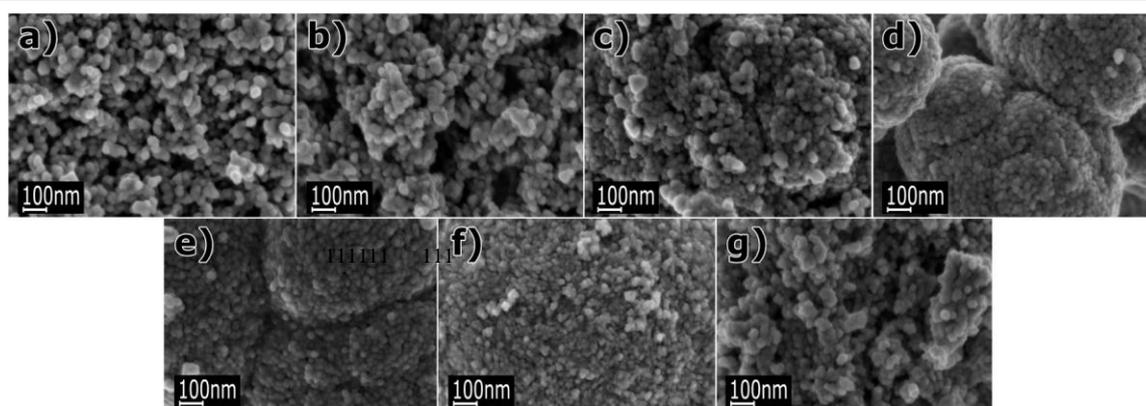


Figure 3: SEM images of NPs of $\text{Zn}_{1-x}\text{Mn}_x\text{O}$ with dopant concentrations of: a) 0 mol %, b) 1 mol %, c) 5 mol %, d) 10 mol %, e) 15 mol %, f) 20 mol % and g) 25 mol %.

Figure 3 and Figure 4 present representative SEM images of $\text{Zn}_{1-x}\text{Mn}_x\text{O}$ NPs. They show particles with homogeneously distributed spherical shapes. An impact of the content of Mn^{2+} dopant on the morphology of $\text{Zn}_{1-x}\text{Mn}_x\text{O}$ powder was observed. Powders with dopant contents of 5, 10, 15, 20 and 25 mol % are composed of dense structures forming conglomerates whose shape resembles the structure of a cauliflower (Figure 4). In the case of dopant contents of 0 or 1 mol %, loose Nanopowder

was obtained. It can be noticed that the average particle size decreases with increasing content of Mn^{2+} dopant in the NPs. The average particle size decreases from circa 30–35 nm to 15–25 nm with an increase in the content of Mn^{2+} dopant from 0 to 20 mol %. In the case of the powder with a dopant content of 25 mol %, the average particle size was circa 20–25nm. SEM tests reveal that each precursor composition must be treated individually. That means that synthesis parameters must be optimized for each precursor composition in order to eliminate the process of agglomeration and formation of conglomerates of $Zn_{1-x}Mn_xO$ NPs.

PHASE COMPOSITION

The XRD tests of the samples did not reveal a presence of foreign phases in the obtained $Zn_{1-x}Mn_xO$ NPs, and all diffraction peaks can be attributed to the hexagonal phase ZnO (Figure 5). Zinc oxide is characterized by hexagonal wurtzite structure (JCPDS No. 36-1451, space group: $P6_3mc$) with two lattice parameters a and c [4]. The parameters of ZnO crystalline lattice assume the values $a = 3.2498 \text{ \AA}$ and $c = 5.2066 \text{ \AA}$, where its c/a ratio of 1.6021 is close to that of a close-packed hexagonal structure (hcp) $c/a = 1.6330$. MnO has rock salt structure (space group: $Fm-3m$) with the lattice parameter $a = 4.4475 \text{ \AA}$. The radius of Mn^{2+} ions is bigger than that of Zn^{2+} ions by 0.08 \AA , which explains the considerable changes in the lattice parameters (Table 2). Both lattice parameters a and c increase with increasing dopant content from 1 to 25 mol % (Figure 6). The results of the c/a lattice parameter ratio reveals that the change of the dopant content in $Zn_{1-x}Mn_xO$ leads to a change in the proportions of the unit cell dimensions (Table 2). The obtained results of crystallite sizes d_a and d_c (Table 3, Figure 7) indicate that the increase of Mn^{2+} - dopant content in ZnO leads to changes in proportions (asymmetry) of crystallite sizes.. If the d_c/d_a ratio assumes a value of different from 1, means particles exhibit a spherical/ elliptical shape.

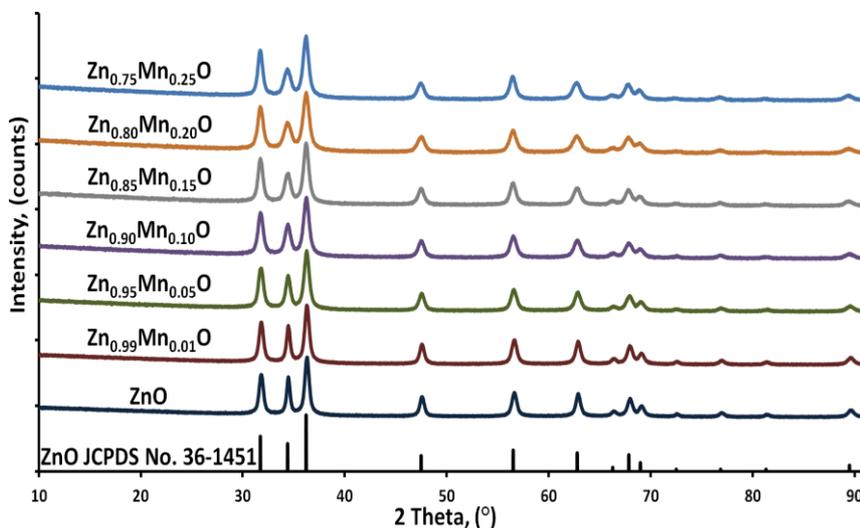


Figure 5: XRD diffraction patterns of $Zn_{1-x}Mn_xO$ NPs, with the nominal dopant content in the solution being 0, 1, 5, 10, 15, 20, 25 mol % and its comparison with the standard pattern of wurtzite-phase ZnO (JCPDS No. 36-1451).

Table 2: Lattice parameters and ratio of lattice parameters of the obtained Zn_{1-x}Mn_xO NPs.

	$\bar{a} \pm \sigma$ [Å]	$\bar{c} \pm \sigma$ [Å]	ratio c/a	\bar{c}/\bar{a} in hcp ZnO
ZnO (JCPDS No. 36-	3.2498	5.2066	1.6021	1.6330
ZnO	3.2499 ± 0.0001	5.2066 ± 0.0003	1.6021	
Zn _{0.99} Mn _{0.01} O	3.2506 ± 0.0002	5.2072 ± 0.0004	1.6019	
Zn _{0.95} Mn _{0.05} O	3.2523 ± 0.0003	5.2092 ± 0.0006	1.6017	
Zn _{0.90} Mn _{0.10} O	3.2535 ± 0.0004	5.2111 ± 0.0004	1.6017	
Zn _{0.85} Mn _{0.15} O	3.2564 ± 0.0005	5.2138 ± 0.0008	1.6011	
Zn _{0.80} Mn _{0.20} O	3.2564 ± 0.0004	5.2146 ± 0.0004	1.6013	
Zn _{0.75} Mn _{0.25} O	3.2593 ± 0.0005	5.2174 ± 0.0008	1.6008	

Despite the presence of as much as 25 mol % dopant in the precursor solution, no foreign phases in the form of Zn MnO₃, Zn Mn₂O₄, metallic Mn, or Mn_xO_y were observe of foreign phase detectability in the diffraction method (XRD) can be as high as 5–6 atom % in the synthesis product, which proves that the organic solvent selected by us (ethylene glycol) prevented competitive reactions and a change of the oxidization state of Mn²⁺ in the course of the synthesis.

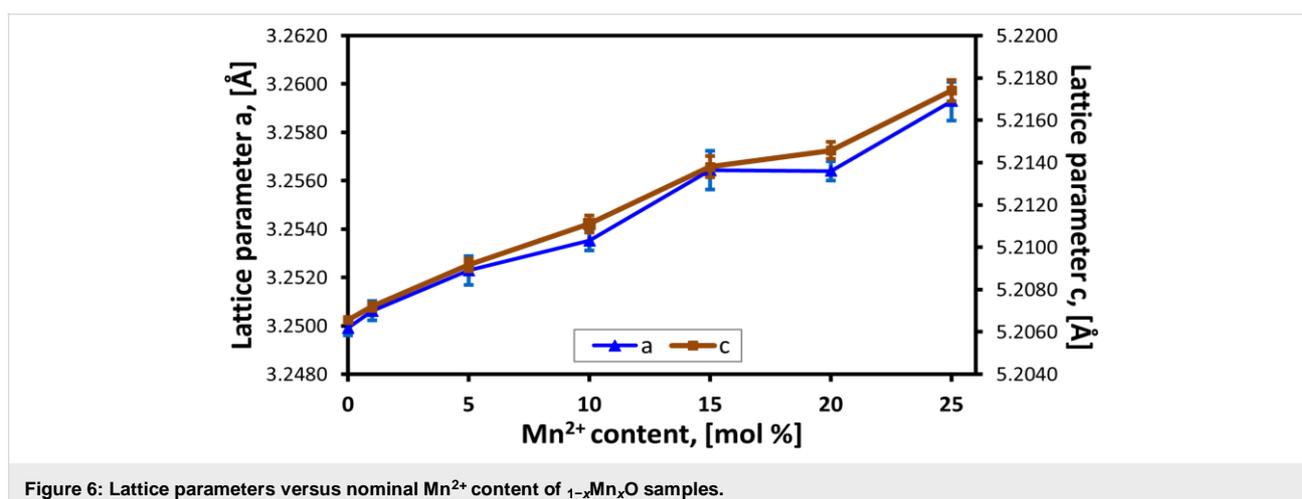


Figure 6: Lattice parameters versus nominal Mn²⁺ content of _{1-x}Mn_xO samples.

Table 3: Crystallite sizes and size ratios of the obtained Zn_{1-x}Mn_xO NPs.

Sample	average crystallite size, d_a	calculated through Scherrer's formula d_c	size ratio
ZnO	22	28	1.273
Zn _{0.99} Mn	21	26	1.238
Zn _{0.95} Mn	18	19	1.056
Zn _{0.90} Mn	17	15	0.882
Zn _{0.85} Mn	18	15	0.833
Zn _{0.80} Mn	16	12	0.750
Zn _{0.75} Mn	19	13	0.684
0.25O			

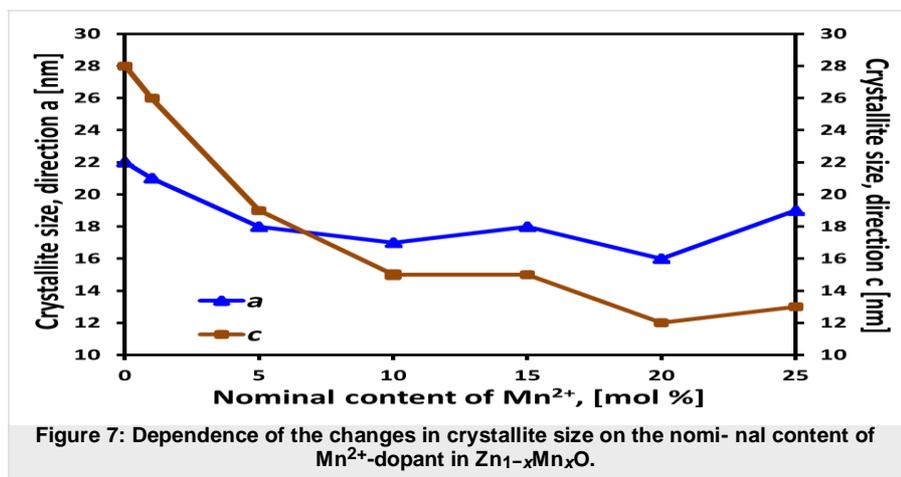


Figure 7: Dependence of the changes in crystallite size on the nominal content of Mn²⁺-dopant in Zn_{1-x}Mn_xO.

CHEMICAL COMPOSITION AND IMPACT OF DOPANT ON THE COLOUR OF NPs

The real content (RC) of manganese dopant in Zn_{1-x}Mn_xO is presented in Table 4. The RC of dopant in Zn_{1-x} is smaller by circa 78% than the expected value of dopant arising from the nominal content (NC) of the dopant in the precursor solution. The difference in sizes of Zn²⁺ and Mn²⁺ ionic radii is the reason for the low doping efficiency of Zn_{1-x}Mn_xO NPs. The chemical composition analysis was carried out by three methods: ICP-OES, colorimetry and X-ray microanalysis. The most often used methods in the relevant literature are ICP-O and X-ray microanalysis. All the employed methods provided mutually different results (Table 4). This resulted from the limitations and accuracy of the various analytical techniques in relation to the quantitative determination of zinc and manganese. ICP-OES analysis is regarded as the most accurate and precise method. Figure 8 describes the correlation between NC in the precursor and RC of Mn²⁺ dopant in NPs. The average efficiency of doping during the synthesis of Zn_{1-x}Mn_xO in ethylene glycol was merely 22 mol %, being four times smaller than in the case of doping ZnO with Co²⁺ ions [66]. The derived formula ($y = -0.0057x^2 + 0.353x - 0.0447$, where y is the real and x is the nominal dopant content) enables the control of RC of the dopant in Zn_{1-x}Mn_xO NPs at the stage of precursor preparation. The nominal contents of manganese dopant in Zn_{1-x}Mn_xO were used for denominating the samples in this paper. The doping of zinc oxide with Mn²⁺ ions leads to a change in the optical properties of the material, which is proved by the change of the sample colour (Figure 9 and Figure 10). The obtained Zn_{1-x}Mn_xO NPs, depending on the Mn²⁺-dopant content, have differing shades of yellow and orange. The intensity of NPs color depends on the dopant content, which is illustrated in Figure 9 and Figure 10. Most of the Zn_{1-x}Mn_xO nanostructure materials exhibit strong absorption in the UV and visible range and a strong UV emission [30].

DENSITY, SPECIFIC SURFACE AREA AND CRYSTALLITE SIZE DISTRIBUTION

The theoretical density of ZnO is 5.606 g/cm³. The pycnometric density of the obtained reference sample of ZnO NPs without doping amounted to 5.09 g/cm³. The difference between the nano density and the theoretical density of ZnO can result above all from surface defects, the presence of Zn(OH)₂ hydroxides and the nonstoichiometric composition. The density of Zn_{1-x}Mn_xO, irrespectively of the content of Mn²⁺ dopant, was constant at about 5.0 g/cm³. The lower density of Zn_{1-x}Mn_xO is related to the smaller atomic weight of Mn (54.93 u) in comparison with the Zn atoms (65.38 u) in Zn_{1-x}Mn_xO, and to the possible presence of a greater quantity of defects in the crystalline lattice. The specific surface area of Zn_{1-x}Mn_xO ranged from 40 to 70 m²/g (Table 5). The average size of

Zn_{1-x}Mn_xO particles calculated based on the specific surface area ranged from 17 to 30nm (Table 5). Based on the XRD analysis using the Nanopowder XRD Processor Demo web application, the average size and the size distribution of crystallites were determined for Zn_{1-x}Mn_xO NPs (Figure 11). Zn_{1-x}Mn_xO material was characterized by an average crystal- lite size from 19 to 26 nm (Table 5), with a narrow distribution, which ranged from 30–35 nm to 40–60 nm depending on the dopant content (Figure 11). When comparing the obtained results from the Nanopowder XRD Processor Demo application and with that from Scherrer’s formula, similar crystallite sizes were obtained. The results fall within the range of the standard deviation of methods (Table 5).

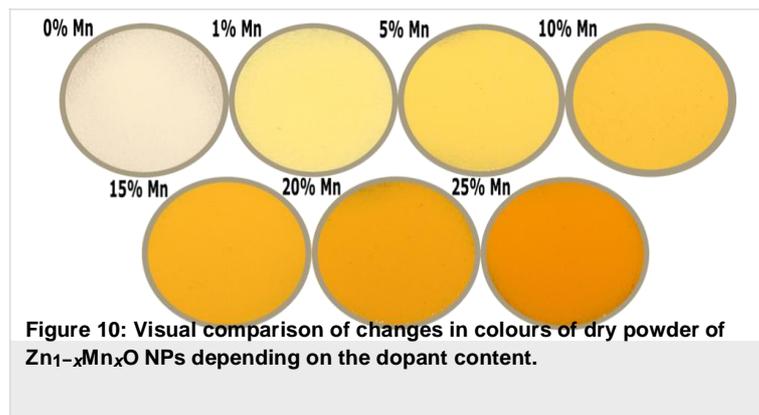


Table 5: Characteristic of the Zn_{1-x}Mn_xO NPs samples.

Sample	specific surface area by gas adsorption, $a_s \pm \sigma$ [m ² /g]	skeleton density by gas pycnometry, d_s [g/cm ³]	average particle size from SSA, d_p [nm]	average crystallite size from Nanopowder XRD, d_c [nm]	average crystallite size from Scherrer’s \hat{d}_a [nm]	average crystallite size d_c [nm]
ZnO	42±1	5.09±0.04	28±1	26±8	22	28
Zn _{0.99} Mn	40±1	4.98±0.05	30±1	24±8	21	26
Zn _{0.95} Mn	50±1	4.95±0.03	24±1	21±6	18	19
Zn _{0.90} Mn	60±1	5.03±0.04	20±1	19±6	17	15
Zn _{0.85} Mn	57±1	5.01±0.04	21±1	20±7	18	15
Zn _{0.80} Mn	70±1	4.97±0.03	17±1	19±10	16	12
Zn _{0.75} Mn	63±1	4.97±0.04	19±1	21±9	19	13
0.25O	1					

The particle sizes calculated based on the specific surface are with an accuracy of 2–6 nm, which confirms that: the nano-particles are monocrystalline;

- the formed structures of nano-particles conglomerates (Figure 2 and Figure 3) do not form aggregates;
- the size of crystallites is equal to the size of nanoparticles, thanks to which these expressions can be used inter- changeably in this paper;
- The obtained crystallite size distribution may be interpreted as particle size distribution.

CONCLUSIONS

Zn_{1-x}Mn_xO ($x = 0.01, 0.05, 0.10, 0.15, 0.2, 0.25$) nanoparticles have been synthesized by microwave solvothermal synthesis. Zinc and manganese acetates dissolved in ethylene glycol were used as precursor. Crystalline Zn_{1-x}Mn_xO NPs with hexagonal wurtzite structure, pure in terms of phase, were obtained. Zn_{1-x}Mn_xO was characterized by an average particle size between 17 and 30 nm, a specific surface area between 40 and 70 m²/g and a density of circa 5.0 g/cm³. The average crystallite size was observed to decrease in line with an increase in the Mn²⁺ content. SEM images did not reveal an impact of the dopant on the spherical shape of nanoparticles. However, an impact of an increase in the Mn²⁺ dopant content on the shape of agglomerates and conglomerates of Zn_{1-x}Mn_xO nano-particles was observed. The crystalline lattice parameters a and c in Zn_{1-x}Mn_xO increase in line with the dopant growth, which is a consequence of the greater ionic radius of Mn²⁺ dopant. The results confirm the usability of the developed method for obtaining crystalline Zn_{1-x}Mn_xO, pure in terms of phase, with a narrow particle size distribution with the nominal dopant content reaching 25 mol % and doping efficiency of circa 22%. Our paper also indicates a high potential of microwave thermal synthesis for obtaining doped ZnO nano-particles.

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